

500 V, 150 mA PNP high-voltage low VCEsat transistor

9 August 2022

**Product data sheet** 

### 1. General description

PNP high-voltage low  $V_{\mbox{CEsat}}$  transistor in a SOT23 small Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability  $I_C$  and  $_{ICM}$
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

### 3. Applications

- Electronic ballasts
- LED driver for LED chain module
- LCD backlighting
- Automotive motor management
- Flyback converters
- Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

## 4. Quick reference data

Table 1. Quick	reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V	-	-	-500	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-500	V
I <sub>C</sub>	collector current		-	-	-0.15	А
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -10 V; I <sub>C</sub> = -10 mA; T <sub>amb</sub> = 25 °C	100	160	300	

# nexperia

### 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	C
2	E	emitter		J
3	С	collector		в-К
			1 2 SOT23	sym013

## 6. Ordering information

#### Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PBHV9050T-Q		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	<u>SOT23</u>		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBHV9050T-Q	LL%

[1] % = placeholder for manufacturing site code

## 8. Limiting values

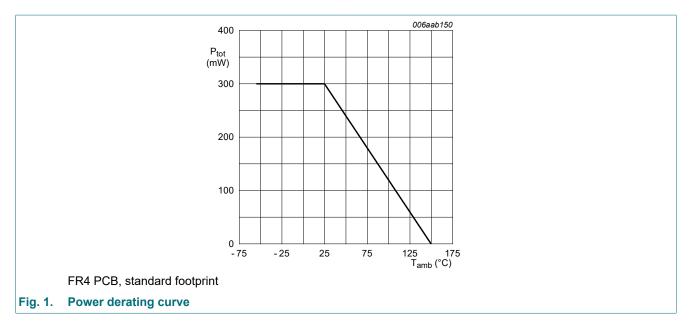
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-500	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-500	V
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V		-	-500	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-6	V
I <sub>C</sub>	collector current			-	-0.15	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-0.5	А
I <sub>BM</sub>	peak base current			-	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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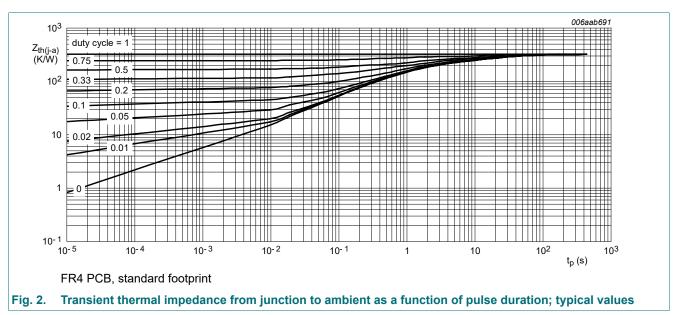


### 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	70	K/W

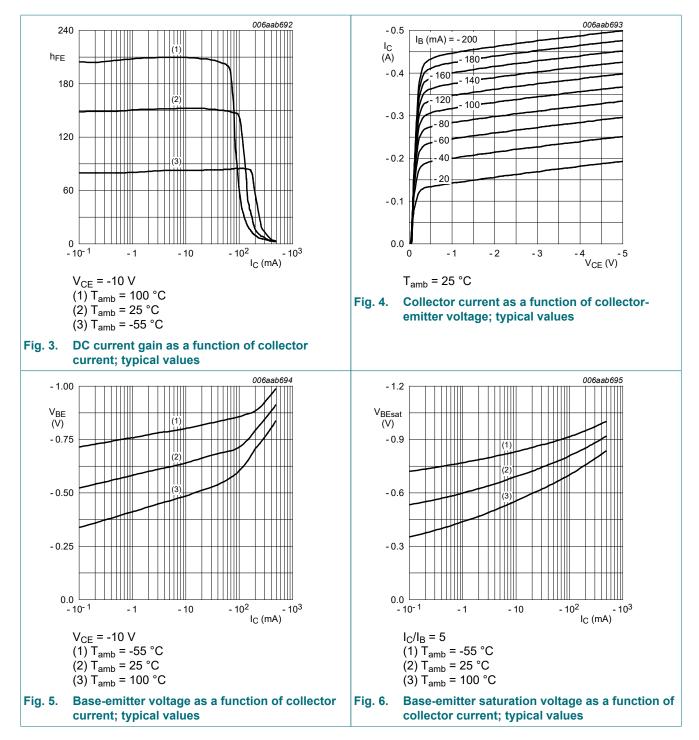
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



# **10. Characteristics**

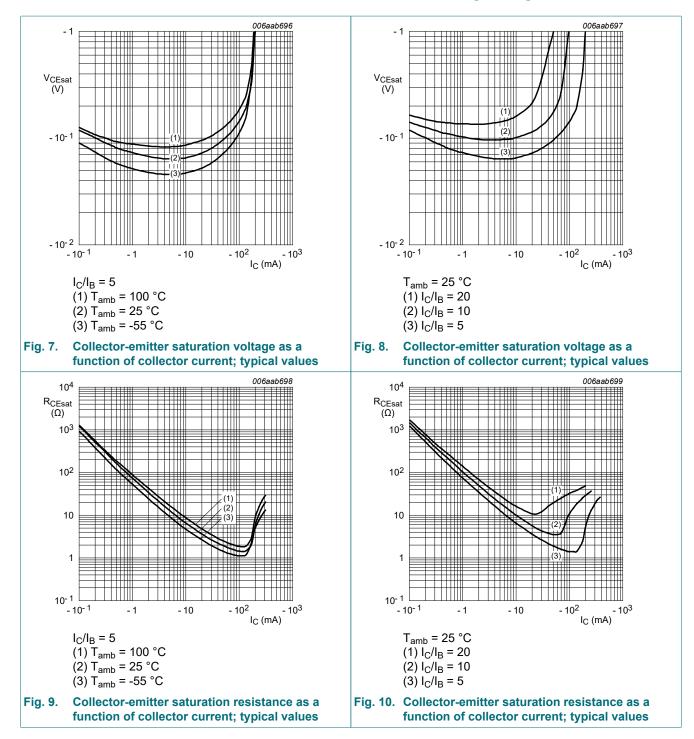
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub> collect	collector-base cut-off	V <sub>CB</sub> = -360 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
	current	V <sub>CB</sub> = -360 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-10	μA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE}$ = -360 V; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -10 V; I <sub>C</sub> = -10 mA; T <sub>amb</sub> = 25 °C	100	160	300	
		$V_{CE}$ = -10 V; I <sub>C</sub> = -50 mA; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	80	160	300	
V <sub>CEsat</sub>		I <sub>C</sub> = -20 mA; I <sub>B</sub> = -2 mA; T <sub>amb</sub> = 25 °C	-	-115	-200	mV
	saturation voltage	$I_{C}$ = -50 mA; $I_{B}$ = -10 mA; $T_{amb}$ = 25 °C	-	-95	-200	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C}$ = -50 mA; $I_{B}$ = -10 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-0.75	-0.9	V
t <sub>d</sub>	delay time	V <sub>CC</sub> = -20 V; I <sub>C</sub> = -0.05 A; I <sub>Bon</sub> = -5 mA;	-	75	-	ns
t <sub>r</sub>	rise time	I <sub>Boff</sub> = 10 mA; T <sub>amb</sub> = 25 °C	-	1600	-	ns
t <sub>on</sub>	turn-on time	-	-	1675	-	ns
t <sub>s</sub>	storage time	_	-	1200	-	ns
t <sub>f</sub>	fall time	-	-	550	-	ns
t <sub>off</sub>	turn-off time		-	1750	-	ns
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -10 V; I <sub>C</sub> = -10 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	-	50	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -20 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	6	-	pF
C <sub>e</sub>	emitter capacitance	V <sub>EB</sub> = -0.5 V; I <sub>C</sub> = 0 A; i <sub>c</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	170	-	pF

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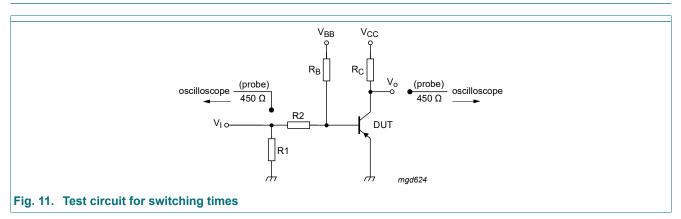


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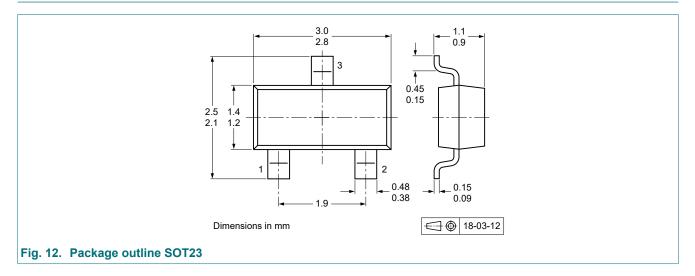
# **11. Test information**



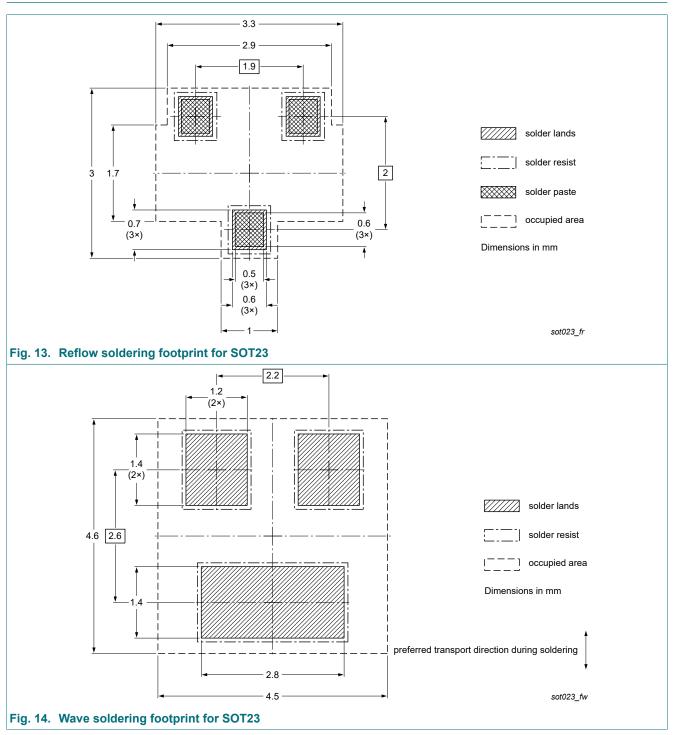
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 12. Package outline



# 13. Soldering



# 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBHV9050T-Q v.1	20220809	Product data sheet	-	-		

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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